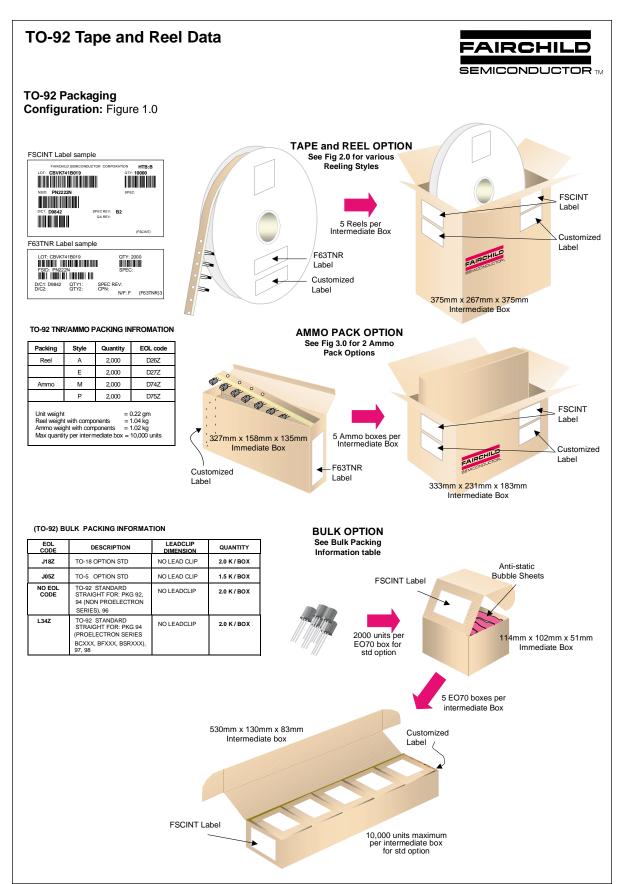
N-Channel Switch

(continued)

Symbol	Parameter Test Conditions				Max	Units
OFF CHAF	RACTERISTICS					
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_G = 1.0 \mu A, V_{DS} = 0$		- 30		V
I _{GSS}	Gate Reverse Current	V _{GS} = - 15 V, V _{DS} = 0			- 1.0	nA
		$V_{GS} = -15 \text{ V}, V_{DS} = 0, T_A =$	150°C		- 0.2	μΑ
V _{GS(off)}	Gate-Source Cutoff Voltage	$V_{DS} = 20 \text{ V}, I_{D} = 1.0 \text{ nA}$	4391	- 4.0	- 10	V
			4392 4393	- 2.0 - 0.5	- 5.0 - 3.0	V V
V _{GS(f)}	Gate-Source Forward Voltage	$I_G = 1.0 \text{ mA}, V_{DS} = 0$	4393	- 0.5	1.0	V
I _{D(off)}	Drain Cutoff Leakage Current	V _{DS} = 20 V, V _{GS} = - 12 V	4391		0.1	nA
·D(OII)	J.a Cato Ioanage Carroni	$V_{DS} = 20 \text{ V}, V_{GS} = -7.0 \text{ V}$	4392		0.1	nA
		$V_{DS} = 20 \text{ V}, V_{GS} = -5.0 \text{ V}$	4393		0.1	nA
		V _{DS} = 20 V, V _{GS} = - 12 V,	4004		0.2	
		$T_A = 150^{\circ}C$ $V_{DS} = 20 \text{ V}, V_{GS} = -7.0 \text{ V},$	4391		0.2	μΑ
		$T_A = 150^{\circ}C$	4392		0.2	μΑ
		V _{DS} = 20 V, V _{GS} = - 5.0 V,			0.0	
		T _A = 150°C	4393		0.2	μΑ
ON CHAR	ACTERISTICS					
I _{DSS}	Zero-Gate Voltage Drain Current*	V _{DS} = 20 V, V _{GS} = 0	4391	50	150	mA
טטט	Zoro Gate Voltage Brain Garrent	VDS = 20 V, VGS = 0	4392	25	75	mA
			4393	5.0	30	mA
V _{DS(on)}	Drain-Source On Voltage	$I_D = 12 \text{ mA}, V_{GS} = 0$	4391		0.4	V
		$I_D = 6.0 \text{ mA}, V_{GS} = 0$	4392		0.4	V
	Dunin Course On Besistance	$I_D = 3.0 \text{ mA}, V_{GS} = 0$	4393		0.4	V
r _{DS(on)}	Drain-Source On Resistance	$I_D = 1.0 \text{ mA}, V_{GS} = 0$	4391 4392		30 60	Ω
			4393		100	Ω
SMVII-SI	GNAL CHARACTERISTICS					
	Drain-Source On Resistance	$V_{DS} = V_{GS} = 0$, f= 1.0 kHz	4391		30	Ω
r _{ds(on)}	Brain Codrec On Resistance	VDS = VGS = 0, 1= 1.0 KHZ	4392		60	Ω
			4393		100	Ω
Ciss	Input Capacitance	$V_{DS} = 20, V_{GS} = 0, f = 1.0 M$	lHz		14	pF
C _{rss}	Reverse Transfer Capacitance	V _{GS} = - 12 V, f = 1.0 MHz	4391		3.5	pF
		$V_{GS} = -7.0 \text{ V}, f = 1.0 \text{ MHz}$	4392		3.5	pF
		$V_{GS} = -5.0 \text{ V}, f = 1.0 \text{ MHz}$	4393		3.5	pF
SWITCHI	NG CHARACTERISTICS					
t _r	Rise Time	I _{D(on)} = 12 mA	4391		5.0	ns
		$I_{D(on)} = 6.0 \text{ mA}$	4392		5.0	ns
		$I_{D(on)} = 3.0 \text{ mA}$	4393		5.0	ns
tf	Fall Time	$V_{GS(off)} = 12 V$	4391		15	ns
		$V_{GS(off)} = 6.0 \text{ V}$	4392		20 30	ns ns
	Turn On Time	V _{GS(off)} = 3.0 V	4393			
ton	Turn-On Time	$I_{D(on)} = 12 \text{ mA}$	4391		15 15	ns ns
		$I_{D(on)} = 6.0 \text{ mA}$	4392 4393		15	ns
		$I_{D(on)} = 3.0 \text{ mA}$				
t_ <i>u</i>	Turn-Off Time	\/oo(=#) = 12 \/	4301		20	
t _{off}	Turn-Off Time	$V_{GS(off)} = 12 \text{ V}$ $V_{GS(off)} = 6.0 \text{ V}$	4391 4392		20 35	ns ns

*Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 1.0%

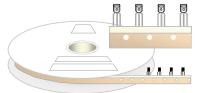


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TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)

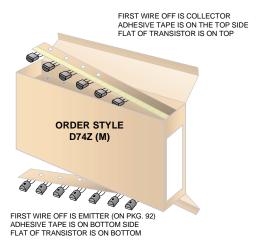


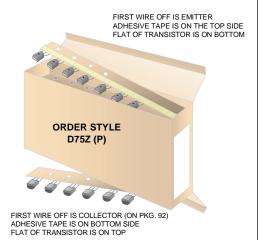
Style "A", D26Z, D70Z (s/h)

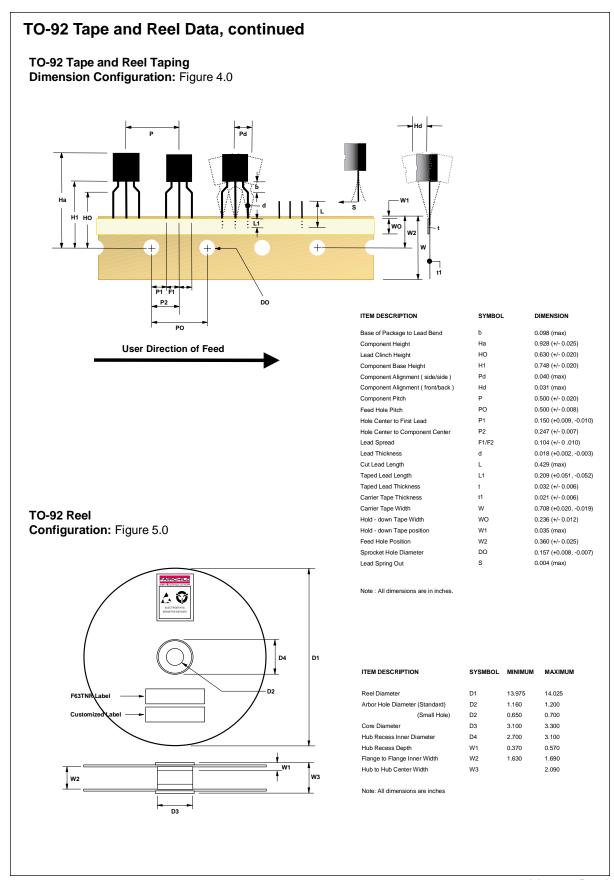
Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0





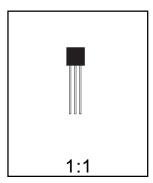


TO-92 Package Dimensions



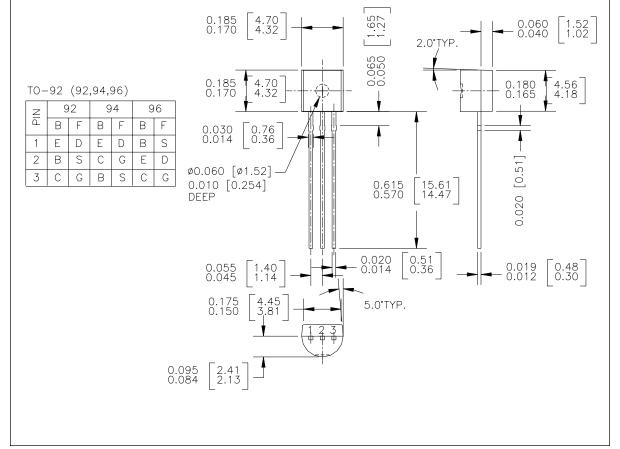
TO-92 (FS PKG Code 92, 94, 96)





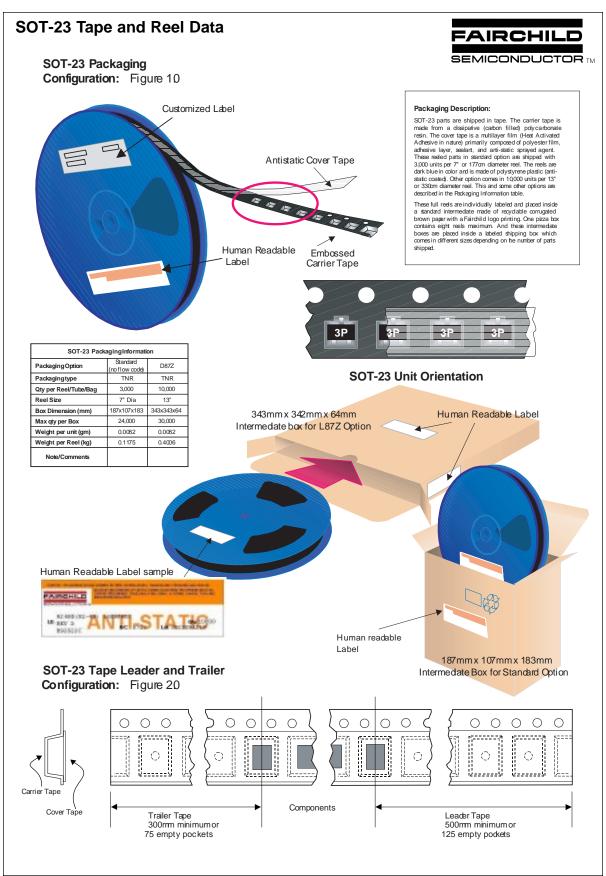
Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.1977



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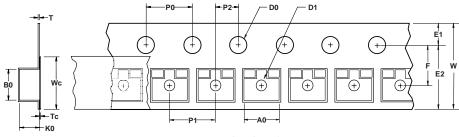
January 2000, Rev. B



SOT-23 Tape and Reel Data, continued

SOT-23 Embossed Carrier Tape

Configuration: Figure 3.0



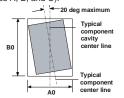
User Direction of Feed	

Dimensions are in millimeter														
Pkg type	Α0	В0	w	D0	D1	E1	E2	F	P1	P0	K0	Т	Wc	Тс
SOT-23 (8mm)	3.15 +/-0.10	2.77 +/-0.10	8.0 +/-0.3	1.55 +/-0.05	1.125 +/-0.125	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.0 +/-0.1	4.0 +/-0.1	1.30 +/-0.10	0.228 +/-0.013	5.2 +/-0.3	0.06 +/-0.02

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation



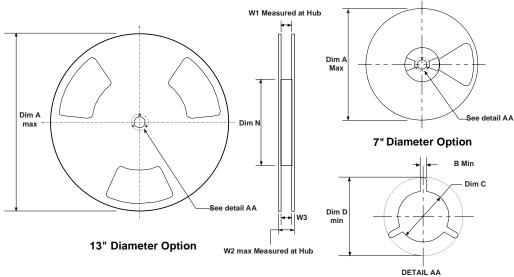
Sketch B (Top View)
Component Rotation



Sketch C (Top View)

Component lateral movement

SOT-23 Reel Configuration: Figure 4.0

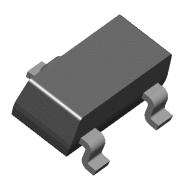


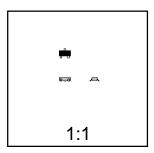
Dimensions are in inches and millimeters									
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2	Dim W3 (LSL-USL)
8mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9
8mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	4.00 100	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9

SOT-23 Package Dimensions



SOT-23 (FS PKG Code 49)

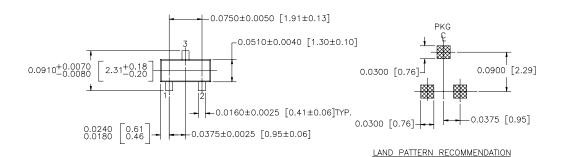


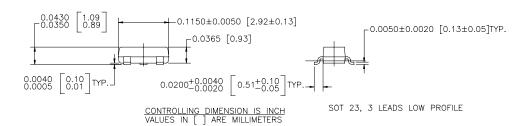


Scale 1:1 on letter size paper

Dimensions shown below are in: inches [millimeters]

Part Weight per unit (gram): 0.0082





NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

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September 1998, Rev. A1

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DOMETM ISOPLANARTM Quiet SeriesTM E²CMOSTM MICROWIRETM SILENT SWITCHER[®]

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